

U.S. Department of Commerce, Patent and Trademark Office					Atty Docket No. 01/28/02		Serial No.	
					M-11547 US		Please assign	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT					Applicants			
(Use several sheets if necessary)					Krames, Michael R.; Sigalas, Mihail M.; Wierer, Jonathan J., Jr.			
					Filing Date		Group	
					Herewith		Unassigned	
U.S. Patent Documents								
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate	
PA	AA	6,307,218 B1	10/23/2001	Steigerwald et al.	257	99		
	AB	5,955,749	9/21/1999	Joannopoulos et al.	257	98		
Foreign Patent Documents								
							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
	AC							
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)								
	AD	Lee et al., "Modified spontaneous emission from a two-dimensional photonic bandgap crystal slab," J. Opt. Soc. Am. B, Vol. 17, No. 8, August, 2000, pp. 1438-1442.						
	AE	Boroditsky et al., "Surface recombination measurements on III-V candidate materials for nanostructure light-emitting diodes," Journal of Applied Physics, Vol. 87, No. 7, April 1, 2000, pp. 3497-3504.						
	AF	Boroditsky et al., "Light extraction from optically pumped light-emitting diode by thin-slab photonic crystals," Applied Physics Letters, Vol. 75, No. 8, August 23, 1999, pp. 1036-1038.						
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	AH	Xu et al., "Finite-difference time-domain calculation of spontaneous emission lifetime in a microcavity," J. Opt. Soc. Am. B, Vol. 16, No. 3, March, 1999, pp. 465-474.						
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	AJ	Fan et al., "High Extraction Efficiency of Spontaneous Emission from Slabs of Photonic Crystals," Physical Review Letters, Vol. 78, No. 17, April 28, 1997, pp. 3294-3297.						
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	AM	Imada et al., "Coherent two-dimensional lasing action in surface-emitting laser with triangular-lattice photonic crystal structure," Applied Physics Letters, Vol. 75, No. 3, July 19, 1999, pp. 316-318.						
	AN	Pottage et al., "Vertical-cavity surface-emitting resonances in photonic crystal films," J. Opt. Soc. Am. A, Vol. 18, No. 2, February, 2001, pp. 442-447.						
	AO	Tiwari, S., <i>Compound Semiconductor Device Physics</i> , Academic Press, Inc., San Diego, CA, 1992, pp. 182-186.						
	AP	G.B. Stringfellow and M. George Crawford, eds., <i>High Brightness Light Emitting Diodes</i> , Academic Press, Inc., 1997, Chapter 5, "AlGaInP Light-Emitting Diodes," by F.A. Kish and R. M. Fletcher, pp. 149-170.						
Examiner	Douglas K. Kott				Date Considered 2002 02			
<p>*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.</p>								